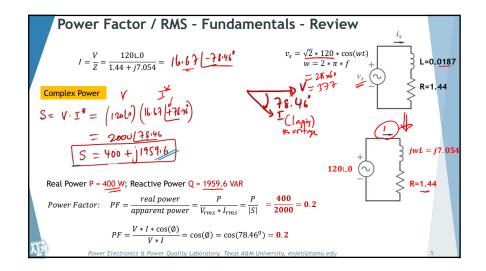
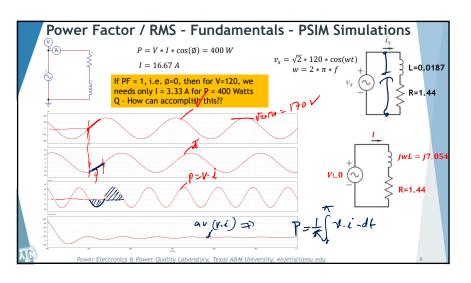
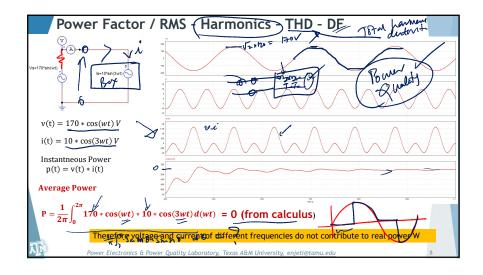
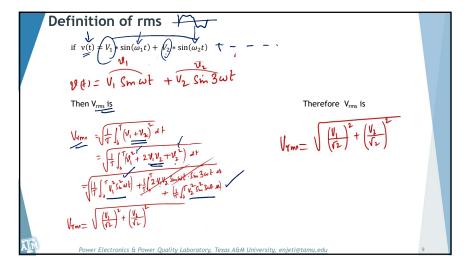


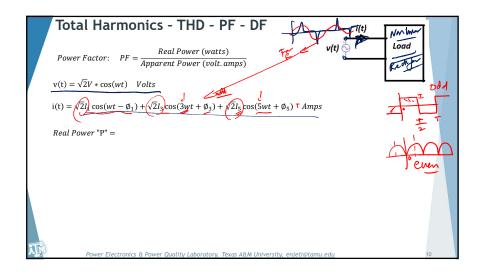
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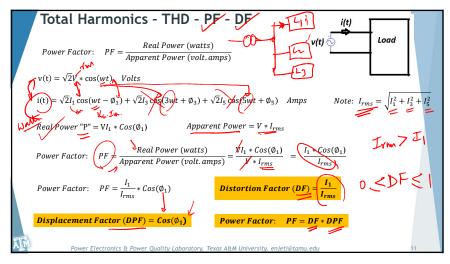


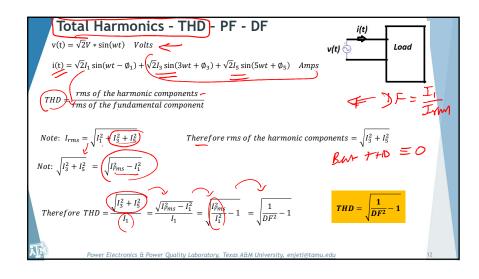


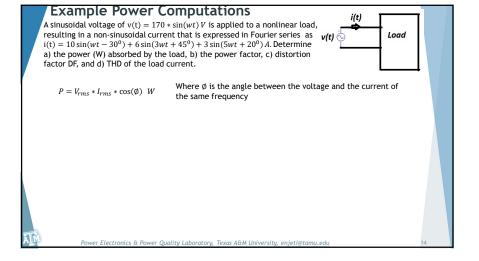






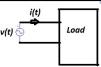






Example Power Computations

A sinusoidal voltage of $v(t) = 170 * \sin(wt) V$ is applied to a nonlinear load, resulting in a non-sinusoidal current that is expressed in Fourier series as v(t) $i(t) = 10 \sin(wt - 30^{\circ}) + 6 \sin(3wt + 45^{\circ}) + 3 \sin(5wt + 20^{\circ}) A$. Determine a) the power (W) absorbed by the load, b) the power factor, c) distortion factor DF, and d) THD of the load current.



$$P = V_{rms} * I_{rms} * \cos(\emptyset) \ W$$

Where \emptyset is the angle between the voltage and the current of the same frequency

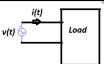
Therefore:
$$P = \frac{170}{\sqrt{2}} * \frac{10}{\sqrt{2}} \cos(30^{\circ}) = 736.12 \ W$$
 $I_{rms} = \sqrt{\left(\frac{10^{2}}{\sqrt{2}}\right) + \left(\frac{6^{2}}{\sqrt{2}}\right) + \left(\frac{3^{2}}{\sqrt{2}}\right)} = 8.515 \ A$

$$I_{rms} = \sqrt{\left(\frac{10^2}{\sqrt{2}}\right) + \left(\frac{6^2}{\sqrt{2}}\right) + \left(\frac{3^2}{\sqrt{2}}\right)} = 8.515 \text{ A}$$

$$PF = \frac{real\ power}{apparent\ power} \qquad = \frac{736.12}{V_{rms}*I_{rms}} \qquad = \frac{736.12}{\frac{170}{\sqrt{2}}*8.515} = 0.72$$

Example Power Computations

A sinusoidal voltage of $v(t) = 170 * \sin(wt) V$ is applied to a nonlinear load, resulting in a non-sinusoidal current that is expressed in Fourier series as v(t) $i(t) = 10\sin(wt - 30^{\circ}) + 6\sin(3wt + 45^{\circ}) + 3\sin(5wt + 20^{\circ}) A$. Determine a) the power (W) absorbed by the load, b) the power factor, c) distortion factor DF, and d) THD of the load current.



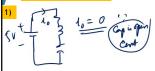
$$DF = \frac{I_1}{I_{YMM}} = \frac{(10/f_2)}{8.575} = 0.83$$

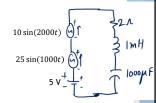
(d) THD =
$$\sqrt{\frac{(6)^{2} + \frac{3}{4}^{2}}{(10)(12)}} = 0.672 \approx 67.2\%$$

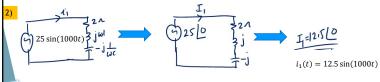
Example Power Computations

A voltage source of $v(t) = 5 + 25\sin(1000t) + 10\sin(2000t)$ V is series combination of 2-ohm resistor, a 1 milli-H inductor and a 1000 micro-F capacitor. Determine the rms current in the circuit, and determine the power absorbed by each component.

Apply Superposition





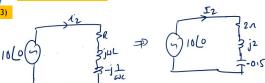


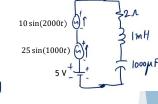
Power Electronics & Power Quality Laboratory, Texas A&M University, enjeti@tamu.edu

Example Power Computations

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Apply Superposition





$$I_{\lambda} = \frac{101^{\circ}}{2+j^{1/5}} = 4 -36.86^{\circ}$$
 $i_{2}(t) = 4\sin(2000t - 36.86^{\circ})$

Example Power Computations

A voltage source of $v(t) = 5 + 25\sin(1000t) + 10\sin(2000t)$ V is series combination of 2-ohm resistor, a 1 milli-H inductor and a 1000 micro-F capacitor. Determine the rms current in the circuit, and determine the power absorbed by each component.

Apply Superposition

 $i(t) = 0 + 12.5\sin(1000t) + 4\sin(2000t - 36.86^{\circ}) A$

$$I_{7m\eta} = \sqrt{\left(\frac{12.5}{f_2}\right)^2 + \left(\frac{4}{\sqrt{2}}\right)^2} = 9.28 A$$



 $10\sin(2000t)$

25 sin(1000t)

$$P = I_{YMA}^{2}(2) = \frac{172.25 \, \text{Walt}}{\text{consume real power}}$$

$$P = \left(\frac{25}{4}\right) \left(\frac{125}{4}\right) \text{ (a) } + \left(\frac{10}{4}\right) \left(\frac{4}{12}\right) \text{ (a) } \left(\frac{4}{12}\right) \text{ (a) } = \frac{172.25 \, \text{Walt}}{172.25 \, \text{Walt}}$$

